TAIWAN SEMICONDUCTOR

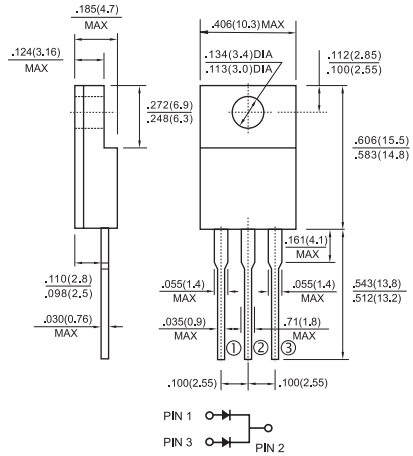
RoHS COMPLIANCE

SFF1601G - SFF1608G

Isolated 16.0 AMPS.
Glass Passivated Super Fast Rectifiers

ITO-220AB





Dimensions in inches and (millimeters)

Features

- ✧ High efficiency, low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss.
- ✧ For use in low voltage, high frequency inventor, free wheeling, and polarity protection application

Mechanical Data

- ✧ Cases: ITO-220AB molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Terminals: Pure tin plated, lead free. solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: As marked
- ✧ High temperature soldering guaranteed: 260°C/10 seconds .0.25",(6.35mm) from case.
- ✧ Weight: 2.24 grams
- ✧ Mounting torque: 5 in – 1bs. max.

Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%

Type Number	Symbol	SFF 1601G	SFF 1602G	SFF 1603G	SFF 1604G	SFF 1605G	SFF 1606G	SFF 1607G	SFF 1608G	Units
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS Voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC Blocking Voltage	V_{DC}	50	100	150	200	300	400	500	600	V
Maximum Average Forward Rectified Current @T_C = 100°C	$I_{(AV)}$	16								A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	125								A
Maximum Instantaneous Forward Voltage @ 8.0A	V_F	0.975				1.3		1.7		V
Maximum DC Reverse Current @T_A=25°C at Rated DC Blocking Voltage @ T_A=100°C	I_R	10 400								uA uA
Maximum Reverse Recovery Time (Note 1)	Trr	35								nS
Typical Junction Capacitance (Note 2)	Cj	80				60				pF
Typical Thermal Resistance (Note 3)	$R_{\theta JC}$	1.5								°C/W
Operating Temperature Range	T_J	-65 to +150								°C
Storage Temperature Range	T_{STG}	-65 to +150								°C

Notes: 1. Reverse Recovery Test Conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
3. Mounted on Heatsink Size of 3" x 5" x 0.25" Al-Plate.

RATINGS AND CHARACTERISTIC CURVES (SFF1601G THRU SFF1608G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

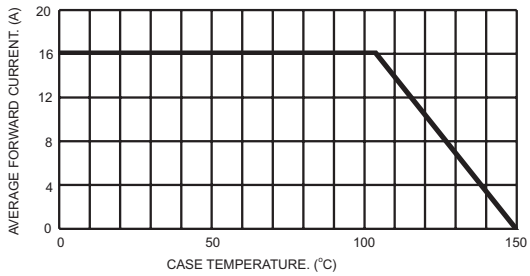


FIG.2- TYPICAL REVERSE CHARACTERISTICS

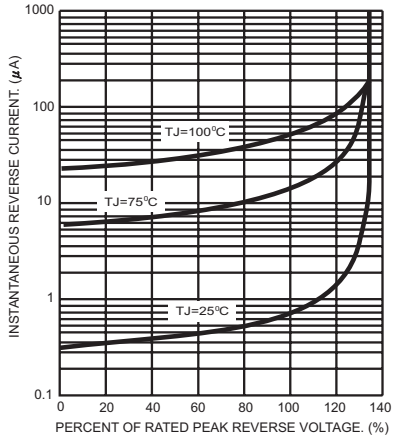


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER LEG

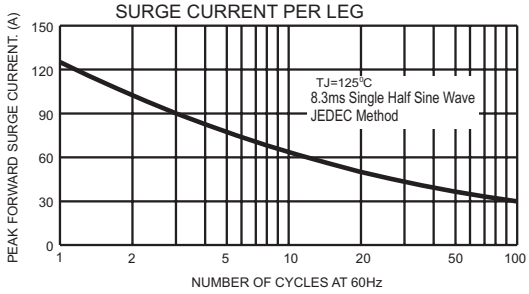


FIG.5- TYPICAL FORWARD CHARACTERISTICS PER LEG

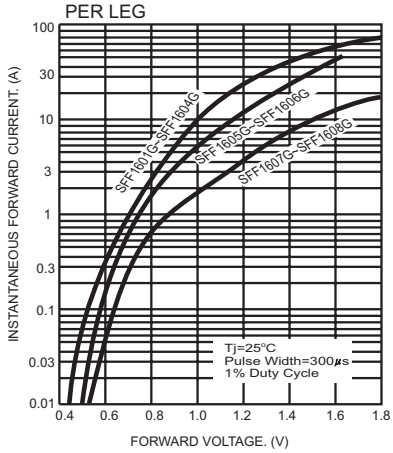


FIG.4- TYPICAL JUNCTION CAPACITANCE PER LEG

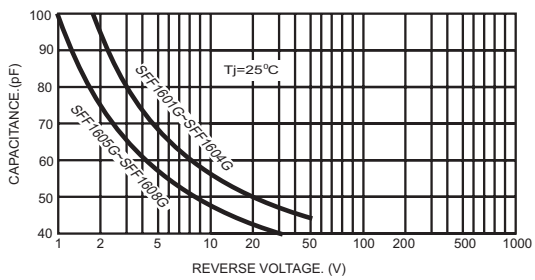


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

